Diode Semiconductor Device - Page 1 of 1



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| | nclosure Material: |
|----|---|
| G | Blass |
| C | overall Length: |
| 0 | .350 inches |
| T | erminal Length: |
| 1 | .000 inches |
| C | overall Diameter: |
| 0 | .145 inches |
| F | unction For Which Designed: |
| Z | ener diode |
| N | Iounting Method: |
| Т | erminal |
| F | eatures Provided: |
| F | lermetically sealed case |
| S | emiconductor Material: |
| S | ilicon |
| ۷ | oltage Rating In Volts Per Characteristic: |
| 1 | 6.0 regulator voltage |
| ۷ | oltage Tolerance In Percent: |
| -{ | 5.0 to 5.0 |
| C | current Rating Per Characteristic: |
| 7 | 5.00 milliamperes voltage regulator diode current |
| P | ower Rating Per Characteristic: |
| 5 | .0 watts small-signal input power, common-collector absolute |
| N | laximum Operating Tempurature Per Measurement Point: |
| 2 | 00.0 degrees celsius ambient air |
| Т | erminal Type And Quantity: |
| 2 | uninsulated wire lead |
| S | pecification Data: |
| 8 | 0131-release 5750 professional/industrial association specification |
| S | helf Life: |
| Ν | l/a |
| ι | nit Of Measure: |
| | |
| C | emilitarization: |
| Ν | lo |
| F | iig: |
| | .110a0 |